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Typical Applications

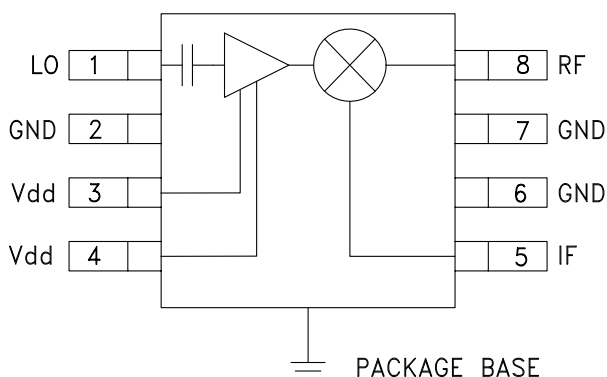
The HMC488MS8G / HMC488MS8GE is ideal for:

- Basestations & Repeaters
- Access Points & Subscribers
- UNII, ISM, WLAN & WiMAX
- Point to Point/Multi-Point Radios
- VSAT Radio

Features

- Low Conversion Loss: 7 dB
- Double-Balanced Topology
- Integrated LO Amplifier: 0 to +6 dBm Drive
- Input IP3: +15 dBm
- Single Supply: +5V @ 46 mA
- MSOP8-G Package: 14.8 mm²

Functional Diagram



General Description

The HMC488MS8G(E) is an ultra miniature double-balanced mixer with integrated LO amplifier in an 8 lead plastic SMT MSOP8-G covering 4 - 7 GHz. This passive MMIC mixer integrates a GaAs Schottky diode quad, transformer baluns and a LO buffer on a single chip yielding a low conversion loss of 7 dB coupled with an input IP3 of +15 dBm. The LO buffer amplifier can be driven from 0 to +6 dBm and requires a single supply of +5V @ 46 mA. The device can be used as an upconverter, downconverter or bi-phase (de)modulator for a variety of point-to-point/multipoint, VSAT, telemetry or broadband WLAN applications.

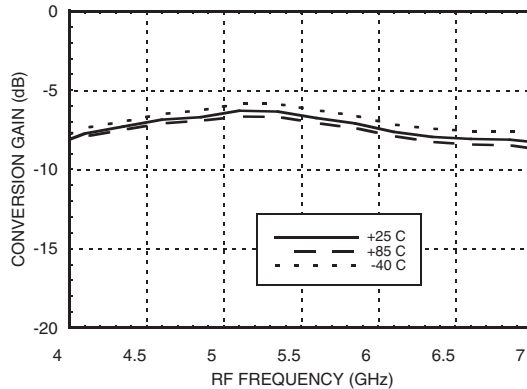
Electrical Specifications, $T_A = +25^\circ \text{C}$, $IF = 100 \text{ MHz}$, $V_{dd} = 5V$

Parameter	LO = +2 dBm			LO = 0 dBm			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range, RF & LO	4 - 7			5 - 6			GHz
Frequency Range, IF	DC - 2.5			DC - 2.5			GHz
Conversion Loss		7	9.5		8	10.5	dB
Noise Figure (SSB)		7			8		dB
LO to RF Isolation	25	30		27	32		dB
LO to IF Isolation	16	20		20	25		dB
IP3 (Input)		15			15		dBm
1 dB Gain Compression (Input)	5	8		6	9		dBm
Supply Current (I _{dd})		46	60		46	60	mA

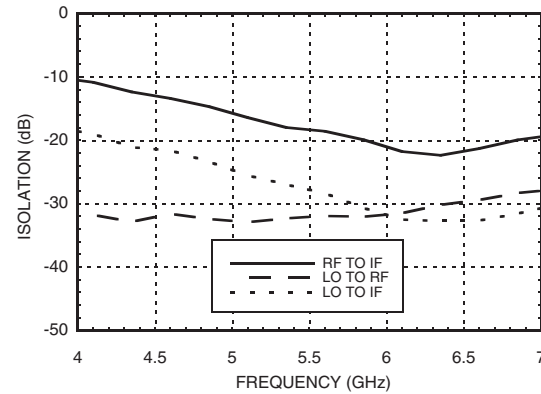
HMC488MS8G / 488MS8GE

GaAs MMIC MIXER W/ INTEGRATED LO AMPLIFIER, 4 - 7 GHz

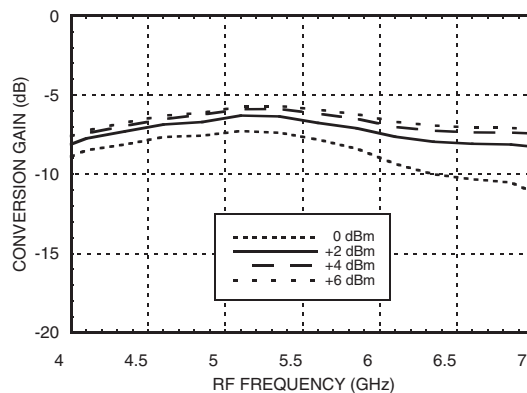
**Conversion Gain vs.
Temperature @ LO = +2 dBm**



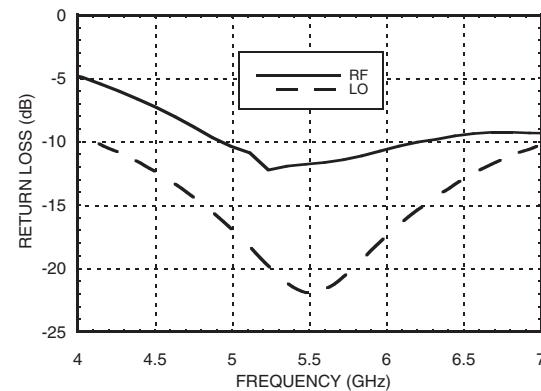
Isolation @ LO = +2 dBm



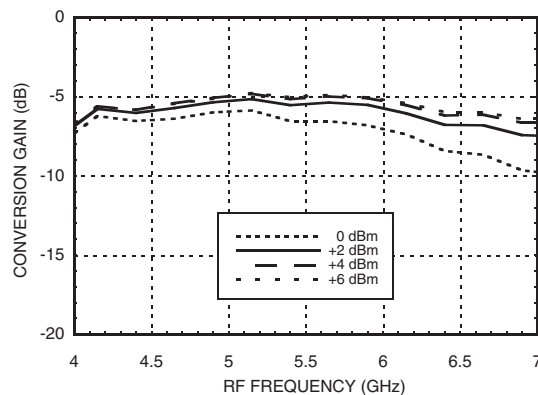
Conversion Gain vs. LO Drive



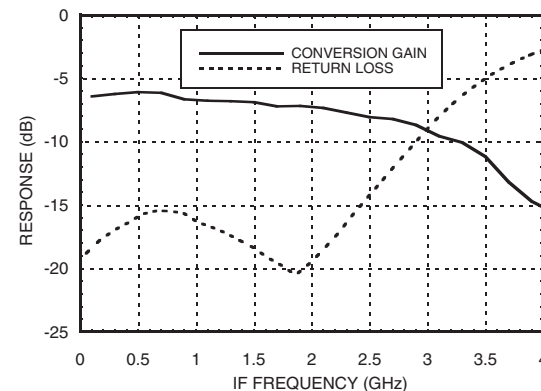
Return Loss @ LO = +2 dBm



**Upconverter Performance
Conversion Gain vs. LO Drive**



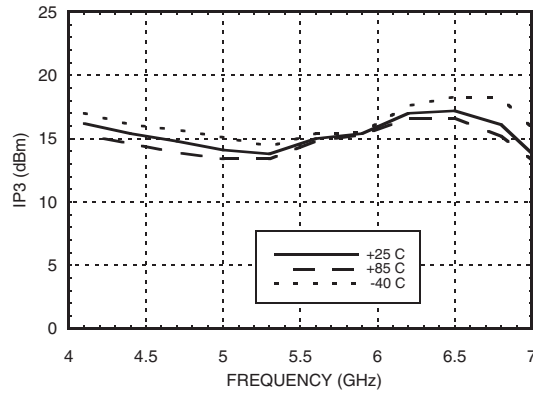
IF Bandwidth @ LO = +2 dBm



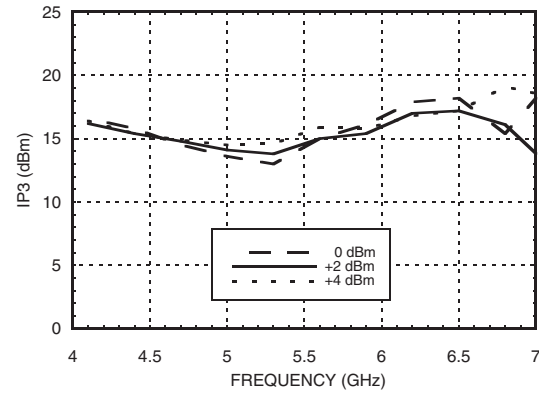
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GaAs MMIC MIXER W/ INTEGRATED LO AMPLIFIER, 4 - 7 GHz

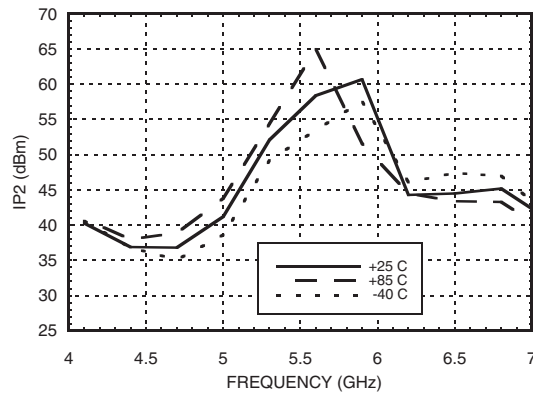
**Input IP3 vs.
Temperature @ LO = +2 dBm**



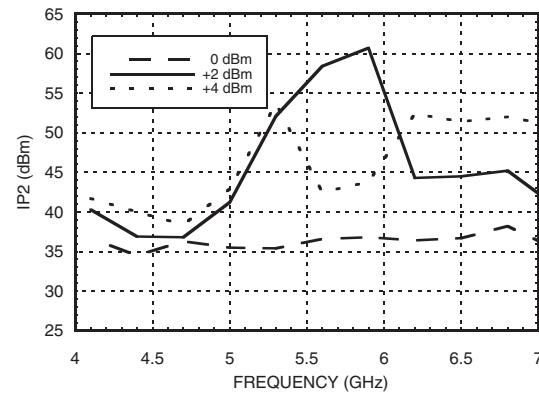
Input IP3 vs. LO Drive



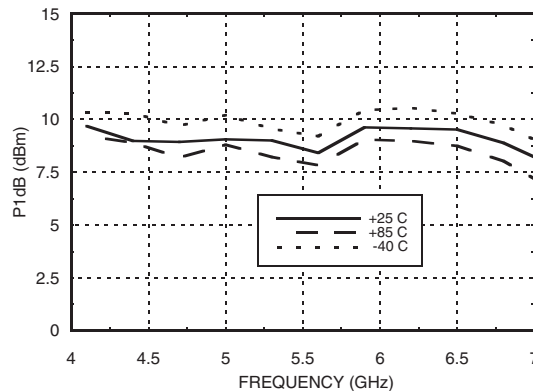
**Input IP2 vs.
Temperature @ LO = +2 dBm**



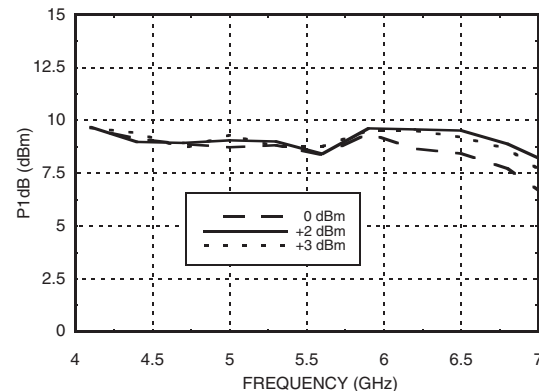
Input IP2 vs. LO Drive



**Input P1dB vs.
Temperature @ LO = +2 dBm**



Input P1dB vs. LO Drive





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GaAs MMIC MIXER W/ INTEGRATED LO AMPLIFIER, 4 - 7 GHz

MxN Spurious @ IF Port

mRF	nLO				
	0	1	2	3	4
0	xx	9	20	24	40
1	12	0	29	52	41
2	62	60	63	60	77
3	77	83	74	63	75
4	83	83	84	85	82

RF Freq. = 5.3 GHz @ -10 dBm
LO Freq. = 5.2 GHz @ +3 dBm
All values in dBc relative to the IF power level.

Harmonics of LO

LO Freq. (GHz)	nLO Spur @ RF Port			
	1	2	3	4
5	32	18	42	52
5.2	32	19	62	56
5.4	31	23	52	59
5.6	31	26	43	64
5.8	31	26	40	57
6	31	27	43	51

LO = +3 dBm
All values in dBc below input LO level measured at RF port.

Typical Supply Current vs. Vdd

Vdd	Idd (mA)
+4.75	45
+5.0	46
+5.25	47

Mixer will operate over full voltage range shown above.

HMC488MS8G / 488MS8GE

**GaAs MMIC MIXER W/ INTEGRATED
LO AMPLIFIER, 4 - 7 GHz**

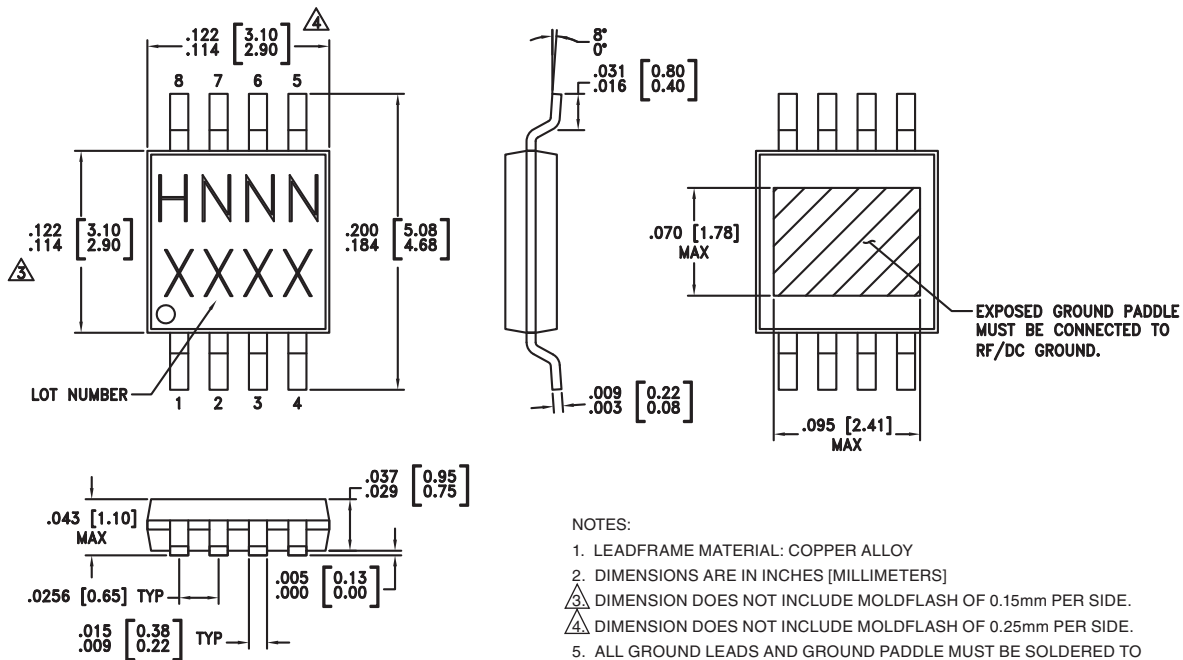
Absolute Maximum Ratings

RF / IF Input (Vdd= +5V)	+13 dBm
LO Drive (Vdd= +5V)	+15 dBm
Vdd	+7 Vdc
Channel Temperature	150°C
Continuous P _{diss} (T = 85°C) (derate 13.2 mW/°C above 85°C)	0.85 W
Thermal Resistance (channel to ground paddle)	75.5 °C/W
Storage Temperature	-65 to +150°C
Operating Temperature	-40 to +85°C
ESD Sensitivity (HBM)	Class 1A



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC488MS8G	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H488 XXXX
HMC488MS8GE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H488 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
 Order On-line at www.hittite.com



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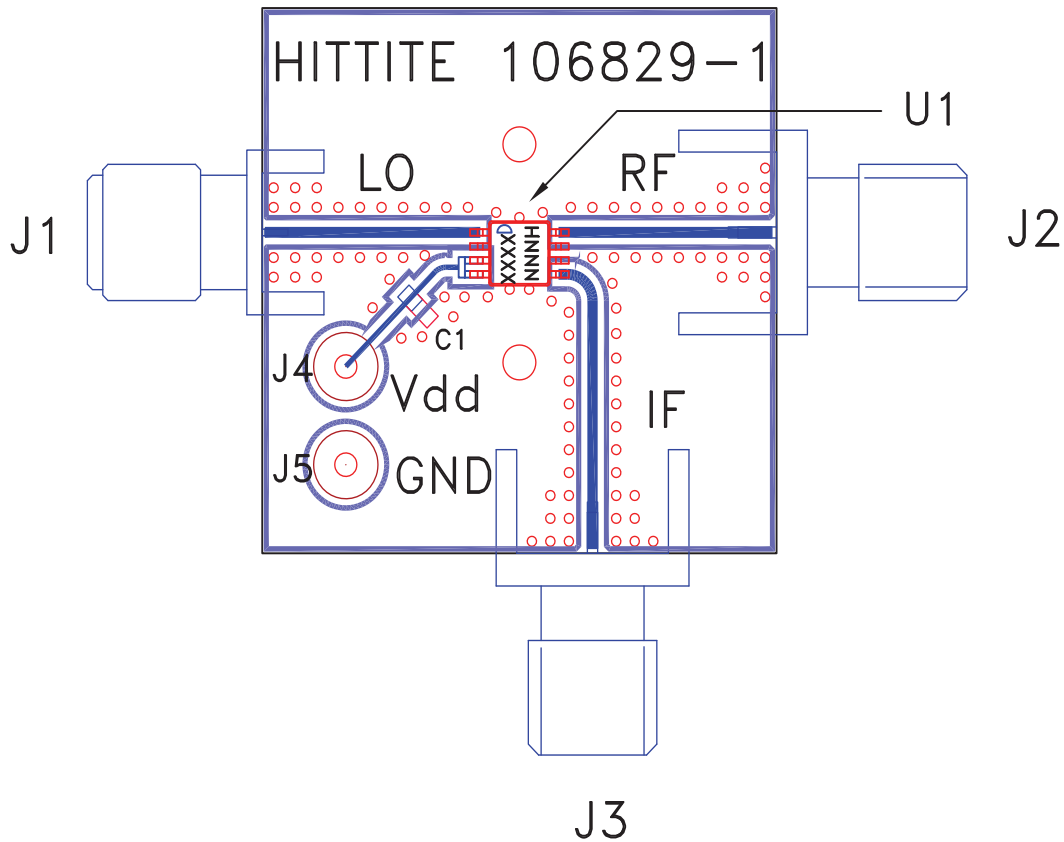
HMC488MS8G / 488MS8GE

GaAs MMIC MIXER W/ INTEGRATED LO AMPLIFIER, 4 - 7 GHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	LO	This pin is AC coupled and matched to 50 Ohms.	
2, 6, 7	GND	This pin must be connected to RF ground.	
3, 4	Vdd	These pins are power supply for LO amp. An external RF bypass capacitor (10,000 pF) is required.	
5	IF	This pin is DC coupled. For applications not requiring operation to DC this port should be DC blocked externally using a series capacitor. Choose value of capacitor to pass IF frequency desired. For operation to DC, this pin must not sink/source more than 40 mA of current or failure may result.	
8	RF	This pin is DC coupled and matched to 50 Ohms.	

Evaluation PCB



List of Materials for Evaluation PCB 108190 ^[1]

Item	Description
J1 - J3	PCB Mount SMA RF Connector
J4 - J5	DC Pins
C1	10,000 pF Chip Capacitor, 0603 Pkg.
U1	HMC488MS8G / HMC488MS8GE
PCB [2]	106829 Evaluation Board, 1.000" x 1.000"

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



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**GaAs MMIC MIXER W/ INTEGRATED
LO AMPLIFIER, 4 - 7 GHz**

Notes:

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MIXERS - DBL-BAL - SMT